

CentralTM Semiconductor Corp.

145 Adams Avenue, Hauppauge, NY 11788 USA
Tel: (631) 435-1110 • Fax: (631) 435-1824

Manufacturers of World Class Discrete Semiconductors

BC237, A, B
BC238, A, B, C
BC239, B, C

NPN SILICON TRANSISTOR

TO-92-18R CASE (CBE)

DESCRIPTION

The CENTRAL SEMICONDUCTOR BC237, BC238, BC239 series types are silicon NPN small signal transistors manufactured by the epitaxial planar process designed for general purpose amplifier applications.

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	BC237	BC238	BC239	UNIT
Collector-Base Voltage	V_{CB0}	50	30	30	V
Collector-Emitter Voltage	V_{CES}	50	30	30	V
Collector-Emitter Voltage	V_{CEO}	45	20	20	V
Emitter-Base Voltage	V_{EBO}	6.0	5.0	5.0	V
Collector Current	I_C		100		mA
Collector Current (PEAK)	I_{CM}		200		mA
Power Dissipation	P_D		300		mW
Operating and Storage Junction Temperature	T_J, T_{STG}		-65 TO +150		$^\circ\text{C}$
Thermal Resistance	θ_{JA}		420		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	BC237		BC238		BC239		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
I_{CES}	$V_{CE}=\text{Rated } V_{CES}$		15		15		15	nA
I_{CES}	$V_{CE}=\text{Rated } V_{CES}, T_A=125^\circ\text{C}$		4.0		4.0		4.0	μA
BV_{CEO}	$I_C=2.0\text{mA}$	45		20		20		V
BV_{EBO}	$I_E=1.0\mu\text{A}$	6.0		5.0		5.0		V
$V_{CE}(\text{SAT})$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.25		0.25		0.25	V
$V_{CE}(\text{SAT})$	$I_C=100\text{mA}, I_B=5.0\text{mA}$		0.60		0.60		0.60	V
$V_{BE}(\text{SAT})$	$I_C=10\text{mA}, I_B=0.5\text{mA}$		0.83		0.83		0.83	V
$V_{BE}(\text{SAT})$	$I_C=100\text{mA}, I_B=5.0\text{mA}$		1.05		1.05		1.05	V
$V_{BE}(\text{ON})$	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$	0.55	0.70	0.55	0.70	0.55	0.70	V

		MIN		MAX		UNIT
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC237A, BC238A)			120	220	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC237B, BC238B, BC239B)			180	460	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC238C, BC239C)			380	800	

		BC237		BC238		BC239		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
f_T	$V_{CE}=5.0\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	150		150		150		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		4.5		4.5		4.5	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$	8.0	TYP	8.0	TYP	8.0	TYP	pF
NF	$V_{CE}=5.0\text{V}, I_C=0.2\text{mA}, R_{GK}=2.0\text{k}\Omega, f=1.0\text{kHz}$		10		10		10	dB

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centrasemi.com

Worldwide Field Representatives:
www.centrasemi.com/wwreps

Worldwide Distributors:
www.centrasemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: www.centrasemi.com/terms